

Features

- ◊ Very low capacitance.
- ◊ Extremely low minority carrier lifetime.
- ◊ Low reverse leakage.
- ◊ Power dissipation $P_d=225\text{mW}$.

Applications

- ◊ Designed primarily for UHF and VHF detector applications.

Ordering Information

| Type No. | Marking | Package Code |
|----------|---------|--------------|
| MMBD452 | 5N | SOT-23 |

MAXIMUM RATING @ $T_a=25^\circ\text{C}$ unless otherwise specified

| Parameter | Symbol | Limits | Unit |
|--------------------------------------|-----------|-------------|------|
| Continuous reverse voltage | V_R | 30 | V |
| Power Dissipation | P_d | 225 | mW |
| Operating junction temperature range | T_J | -55 to +125 | °C |
| Junction and storage temperature | T_{STG} | -55 to +150 | °C |

ELECTRICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified

| Parameter | Symbol | Min. | Typ. | Max. | Unit | Conditions |
|---------------------------|------------|------|--------------|-------------|------|---|
| Reverse Breakdown Voltage | $V_{(BR)}$ | 30 | | | V | $I_R=10\mu\text{A}$ |
| Forward voltage | V_F | | 0.38 0.52 | 0.45 0.6 | V | $I_F=1.0\text{mA}$ $I_F=10\text{mA}$ |
| Reverse current | I_R | | 13 | 200 | nA | $V_R=25\text{V}$ |
| Total Capacitanc | C_T | | 0.9 | 1.5 | pF | $V_R=15\text{V}, f=1\text{MHz}$ |

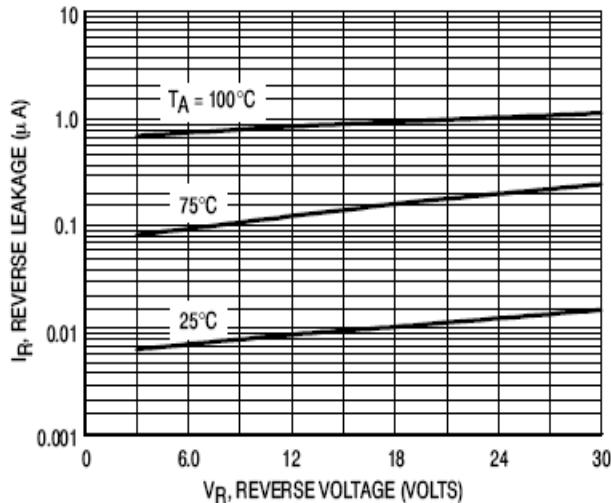
TYPICAL CHARACTERISTICS @ $T_a = 25^\circ C$ unless otherwise specified


Figure 3. Reverse Leakage

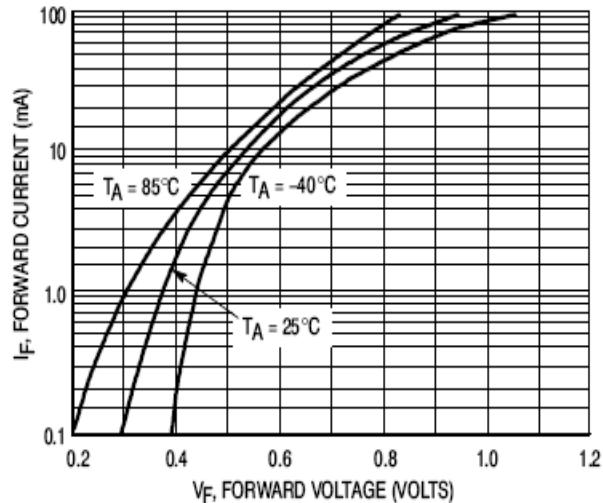


Figure 4. Forward Voltage

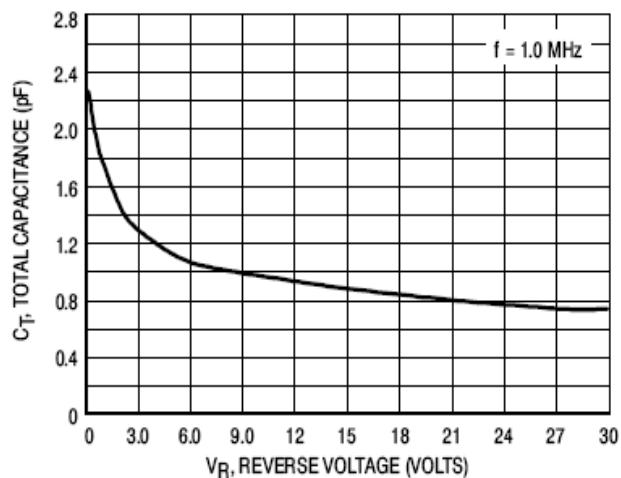


Figure 1. Total Capacitance

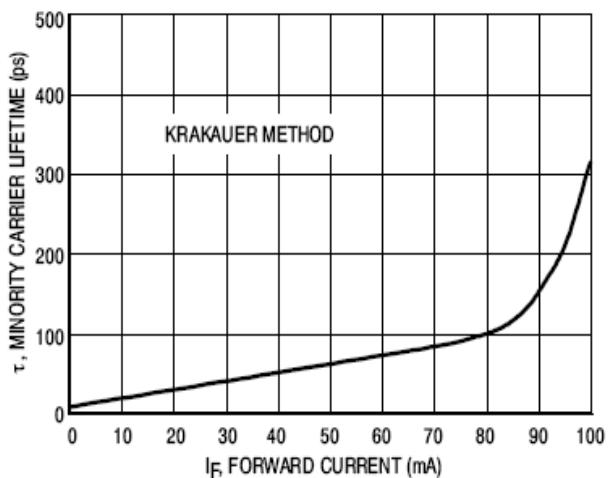


Figure 2. Minority Carrier Lifetime